

REJ03F0165-0200 Rev.2.00 Jun 14, 2006

Description

The M52342FP is IF signal-processing IC for VCRs and TVs. It enables the PLL detection system despite size as small as that of conventional quasi-synchronous VIF/SIF detector, IF/RF AGC, SIF limiter, FM detector, QIF AGC and EQ AMP.

Features

- Video detection output is $2 V_{P-P}$. It has built-in EQ AMP.
- The package is a 24-pin flat package, suitable for space saving.
- The video detector uses PLL for full synchronous detection circuit. It produces excellent characteristics of DG, DP, 920 kHz beat, and cross color.
- Dynamic AGC realizes high-speed response with only single filter.
- Video IF and sound IF signal processing are separated from each other. VCO output is used to obtain intercarrier. This PLL-SPLIT method and built-in QIF AGC provide good sound sensitivity and reduces buzz.
- As AFT output voltage uses the APC output voltage, VCO coil is not used.
- Audio FM demodulation uses PLL system, so it has wide frequency range with no external parts and no adjustment.

Application

TV sets, VCR tuners

Recommended Operating Condition

- In case of V_{CC} and Vreg. OUT short
 - Supply voltage range: 4.75 to 5.25 V
 - Recommended supply voltage: 5.0 V
- Incase of Vreg. OUT open
 - Supply voltage range: 8.5 to 12.5 V



Block Diagram



Pin Arrangement





Absolute Maximum Ratings

(Ta = 25°C, surge protection capacitance 200 pF resistance 0, unless otherwise noted)

Item	Symbol	Ratings	Unit	Condition
Supply voltage1	V _{CC}	13.2	V	V_{CC} and Vreg. OUT is not connected to each other.
Supply voltage Vreg. OUT	Vreg. OUT	6.0	V	V_{CC} and Vreg. OUT is not connected to each other.
Power dissipation	Pd	1524	mW	
Operating temperature	Topr	-20 to +75	°C	
Storage temperature	Tstg	-40 to +150	°C	
Surge voltage resistance	Surge	200	V	

Ambient Operating Condition

 $(Ta = 25^{\circ}C, unless otherwise noted)$

Supply Voltage	Supply Voltage Range	Recommended Supply Voltage				
In case of V_{CC} and Vreg. OUT short	4.75 to 5.25 V	5.0 V				
In case of Vreg. OUT open	8.5 to 12.5 V					

Electrical Characteristics

								(******	5 , 10	- 25	C, ui		nerwise noted)
											Т	est Co	onditions
		Te st					Limits	T		E Pov	Exterr ver Su	nal upply	Switches set to position 1
Item	Sym bol	Ci rc uit	Test Point	Input Point	Input SG	Min.	Тур.	Max.	Unit	V7	V8	V12	unless otherwise indicated
VIF section													
Circuit current1 $V_{CC} = 5V$	I _{CC1}	1	A	VIF IN	SG1	33	46	59	mA			5	V _{CC} = 5V SW17 = 1, SW14 = 2
Circuit current2 $V_{CC} = 12V$	I _{CC2}	1	A	VIF IN	SG1	33	46	59	mA			5	V _{CC} = 12V SW14 = SW17 = 2
Vreg voltage	V _{CC2}	1	TP17			4.60	4.95	5.30	V			5	V _{CC} = 12V SW7 = 2
Video output DC voltage	V18	1	TP18A			3.2	3.5	3.8	V		0		SW8 = 2
Video output voltage	V _o det	1	TP18A	VIF IN	SG1	1.8	2.1	2.4	V _{P-P}				
Video S/N	Video S/N	1	TP18B	VIF IN	SG2	51	56	—	dB				SW18 = 2
Video band width	BW	1	TP18A	VIF IN	SG3	7.0	9.0	—	MHz		Va ria bl e		SW8 = 2
Input sensitivity	VIN MIN	1	TP18A	VIF IN	SG4	-	48	52	dBμ				

$(V_{CC} = 5 \text{ V}, \text{ Ta} = 25^{\circ}\text{C}, \text{ unless otherwise noted})$



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											Т	est Co	onditions
		Те								E	Extern	al	Switches set to
		st					Limits			Pow	ver Su	upply	position 1
		Ci											unless
	Sym	rc	Test	Input	Input								otherwise
Item	bol	uit	Point	Point	SG	Min.	Тур.	Max.	Unit	V7	V8	V12	indicated
Maximum	VIN	1	TP18A	VIF IN	SG5	101	105		dBμ				
allowable	MAX												
input													
AGC	GR					50	57	_	dB				
control	On					00	0.		ab				
range													
input													
IF AGC	V/8	1	TP8	VIE IN	SG6	29	32	35	V				
	vo		110	VII IIN	000	2.5	0.2	0.0	v				
Movimum	∖∕о⊔	1	тро			4.0	4.4		V				
	VOL		100			4.0	4.4		v				
voltage) (OI		TDO		0.07	0.0	0.4	0.0					
Minimum	V8L	1	1P8	VIF IN	SG7	2.2	2.4	2.6	V				
IF AGC													
voltage													
Maximum	V3H	1	TP3	VIF IN	SG6	4.2	4.7	—	V				
RF AGC						8.0	8.9	—					$(V_{CC} = 9V)$
voltage						11.0	11.9						$(V_{CC} = 12V)$
Minimum	V3L	1	TP3	VIF IN	SG7		0.1	0.5	V				
RF AGC							0.2	0.7					$(V_{CC} = 9V)$
voltage							0.2	07					$(V_{cc} = 12V)$
REAGC	V/3	1	TP3		568	80	02	95	dBu				(100 121)
operation	vo	· ·	110	VII IIN	000	00	52	00	uDμ				
voltage													
Capture		1	TD18A		500	1.0	17		МНт				
range II	OL-0		11 107	VII IIN	003	1.0	1.7		1011 12				
Conturo		1			800	10	2.4						
rango	CL-L	· ·	IFIOA	VIETN	369	1.0	2.4						
		4				2.4	4.4		N 41 I				
Capture	CL-1	1				3.1	4.1	_	MHZ				
range i			TDO		0010								
		1	TP2	VIF IN	SG10	20	30	60	mV/			3.3	
sensitivity									kHz				
AFT	V2H	1	TP2	VIF IN	SG10	3.85	4.15	—	V			3.3	
maximum						7.7	8.1	—					$(V_{CC} = 9V)$
voltage						10.7	11.1						$(V_{CC} = 12V)$
AFT	V2L	1	TP2	VIF IN	SG10		0.7	1.2	V			3.3	
minimum							0.7	1.2					$(V_{CC} = 9V)$
voltage							0.7	1.2					$(V_{CC} = 12V)$
AFT	AFT	1	TP2	VIF IN	SG10	2.2	2.5	2.8	V			1.6	(00)
defeat1	def1			•	0010	<u> </u>	1.5	1.0				5	$(1/a_0 - \Omega)/1$
dorodari	aon					4.1	4.5	4.5				U	$(V_{CC} - 9V)$
			TDO		0010	5.5	6.0	0.0	.,				$(V_{CC} = 12V)$
AFI		1	TP2	VIF IN	SG10	2.2	2.5	2.8	V			4.6	
defeat2	def2					4.1	4.5	4.9					$(V_{CC} = 9V)$
						5.5	6.0	6.5					$(V_{CC} = 12V)$
Inter	IM	1	TP18A	VIF IN	SG11	35	40	—	dB		Va		SW8 = 2
modulation											ria		
											bl		
											е		

$(V_{CC} = 5 \text{ V}, \text{ Ta} = 25^{\circ}\text{C}, \text{ unless otherwise noted})$



								$(V_{CC} -$	$5^{v}, 1^{a}$	1 - 25	C, ui	11055 01	inciwise noted)
											Т	est Co	onditions
		Те								E	xtern	nal	Switches set to
		st					Limits			Pov	ver Su	vlaau	position 1
		Ci											unless
	Sym	rc	Test	Input	Input								otherwise
Item	bol	uit	Point	Point	SG	Min.	Tvp.	Max.	Unit	V7	V8	V12	indicated
Differential	DG	1	TP18A	VIF IN	SG12	_	2	5	%				
gain	20			•	0012		-	Ŭ	70				
Differential	DP	1	TP184	VIE IN	SG12		2	5	ded				
nhase			11 10/1	VII IIN	0012		2	Ŭ	ucg				
Sync tin	\/18	1		V/IE IN	562	0.85	1 15	1 45	V				
level	SYNC		11 10/1	VII IIN	002	0.00	1.10	1.45	v				
		2	ТРИ				12		kO				
resister		2	11 4				1.2		1122				
	CINIV	2	TP/				5		nF				
canacitanc	OINV	2	11 4				5		р				
e													
SIE section					l		l						
		1	TD12		802	04	100	106	dDu				
QIF output1	QIFT		1113		SG13	94	100	100	υБμ				
		1	TD12		SG13	04	100	106	dDu				
QIF output?	QIFZ	1	1612		SG14	94	100	100	αьμ				
	N	4	TD40		0014	0.4	100	100	dD			~	014/7 0
SIF	VOS	1	1913		5615	94	100	106	αьμ	0		Э	5007 = 2
	\/1	1	TD10		8020	1.6	2.2	20	V			Б	
	VI	1	IFIU		3620	1.0	2.2	2.0	v			5	
voltage													
	VOAE	1	TP10		SG16	400	560	800	m\/r			5	
(4 5MHz)		1	11 10		3010	400	500	000	ms			5	
		1	TP10		SC21	320	450	630	m\/r			0	
(5 5MHz)	2	1	11 10		5621	520	430	030	ms			0	
		1	TP10	SIE IN	SG16		0.2	0.0	%			5	
distortion	AF1	•	11 10		0010		0.2	0.0	70			J	
(4.5MHz)	/												
AF output	THD	1	TP10	SIF IN	SG21		0.2	0.9	%			0	
distortion	AF2	•		•			0.1	0.0	70			°	
(5.5MHz)													
Limitina	LIM1	1	TP10	SIF IN	SG17		42	55	dBu			5	
sensitivity			_	-	SG19							-	
(4.5MHz)													
Limiting	LIM2	1	TP10	SIF IN	SG22		42	55	dBμ			0	
sensitivity					SG24				•				
(5.5MHz)													
AM	AMR1	1	TP10	SIF IN	SG18	55	62	_	dB			5	
rejection													
(4.5MHz)													
AM	AMR2	1	TP10	SIF IN	SG23	55	64	—	dB			0	
rejection													
(5.5MHz)													
AF S/N	AF	1	TP10	SIF IN	SG20	55	62	—	dB			5	
(4.5MHz)	S/N1												
AF S/N	AF	1	TP10	SIF IN	SG25	55	64	_	dB			0	
(5.5MHz)	S/N2												

 $(V_{CC} = 5 \text{ V}, \text{ Ta} = 25^{\circ}\text{C}, \text{ unless otherwise noted})$



$(V_{CC} = 5 V, Ta = 25^{\circ}C)$, unless otherwise noted)
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											Т	est Co	onditions
		Te st					Limits			E Pov	Extern ver Su	al Ipply	Switches set to position 1
ltem	Sym bol	Ci rc uit	Test Point	Input Point	Input SG	Min.	Тур.	Max.	Unit	V7	V8	V12	unless otherwise indicated
SIF input	RINS	2	TP7			—	1.5		kΩ				
resistance													
SIF input	CINS	2	TP7			—	4		pF				
capacitanc													
е													
Control sect	ion												
QIF	C _{QIF}	1	TP7			—	0.7	1.0	V	Va			SW7 = 2
control										ria			
										bl			
										е			

Pin 14 Voltage Control

Pin 14 Vo	oltage (V)	AF	AFT		
0 to 2.3	0 to 0.6	PAL	NORMAL		
	1.0 to 2.3		DEFEAT		
2.7 to 5.0	2.7 to 4.0	NTSC	NORMAL		
	4.4 to 5.0		DEFEAT		

Electrical Characteristics Test Method

Video S/N

Input SG2 into VIF IN and measure the video out (Pin 22) noise in r.m.s at TP22B through a 5 MHz (-3 dB) L.P.F.

$$S/N = 20 \log \left(\frac{0.7 \bullet Vo det}{NOISE} \right) (dB)$$

BW Video Band Width

- 1. Measure the 1MHz component level of EQ output TP22A with a spectrum analyzer when SG3 (f2 = 57.75 MHz) is input into VIF IN. At that time, measure the voltage at TP10 with SW10, set to position 2, and then fix V10 at that voltage.
- 2. Reduce f2 and measure the value of (f2 f0) when the (f2 f0) component level reaches -3 dB from the 1 MHz component level as shown below.



VIN MIN Input sensitivity

Input SG4 (Vi = 90 dB μ) into VIF IN, and then gradually reduce Vi and measure the input level when the 20 kHz component of EQ output TP22A reaches –3 dB from V₀ det level.

VIN MAX Maximum Allowable Input

- 1. Input SG5 (Vi = 90 dB μ) into VIF IN, and measure the level of the 20 kHz component of EQ output.
- 2. Gradually increase the Vi of SG and measure the input level when the output reaches -3 dB.

GR AGC Control Range

GR = VIN MAX - VIN MIN (dB)

V3 RF AGC Operating Voltage

Input SG8 into VIF IN, and gradually reduce Vi and then measure the input level when RF AGC output TP3 reaches $1/2 V_{CC}$, as shown below.

CL-U Capture Range

- 1. Increase the frequency of SG9 until the VCO is out of locked-oscillation.
- 2. Decrease the frequency of SG9 and measure the frequency fU when the VCO locks. CL-U = fU - 58.75 (MHz)

CL-L Capture Range

- 1. Decrease the frequency of SG9 until the VCO is out of locked-oscillation.
- 2. Increase the frequency of SG9 and measure the frequency fL when the VCO locks. CL-L = 58.75 - fL (MHz)

CL-T Capture Range

CL-T = CL-U + CL-L (MHz)

µAFT Sensitivity, V2H Maximum AFT Voltage, V2L Minimum AFT Voltage

- 1. Input SG10 into VIF IN, and set the frequency of SG10 so that the voltage of AFT output TP2 is 3 V. This frequency is named f (3).
- 2. Set the frequency of SG10 so that the AFT output voltage is 2 V. This frequency is named f (2).
- 3. IN the graph, maximum and minimum DC voltage are V_{2H} and V_{2L} , respectively.

IM Intermodulation

- 1. Input SG11 into VIF IN, and measure EQ output TP22A with an oscilloscope.
- 2. Adjust AGC filter voltage V10 so that the minimum DC level of the output waveform is 1.0 V.
- At this time, measure, TP22A with a spectrum analyzer. The intermodulation is defined as a difference between 920 kHz and 3.58 MHz frequency components.

LIM Limiting Sensitivity

- 1. Input SG17 (SG22) into SIF input, and measure the 400 Hz component level of AF output TP12.
- 2. Input SG19 (SG24) into SIF input, and measure the 400 Hz component level of AF output TP12.
- 3. The input limiting sensitivity is defined as the input level when a difference between each 400 Hz components of audio output (TP12) is 30 dB, as shown below.

AMR AM Rejection

- 1. Input SG18 (SG23) into SIF input, and measure the output level of AF output TP12. This level is named VAM.
- 2. AMR is;

$$AMR = 20 \log \left(\frac{VoAF (mVrms)}{VAM (mVrms)} \right) \quad (dB)$$

AF S/N

- 1. Input SG19 (SG24) into SIF input, and measure the output noise level of AF output TP1. This level is named VN.
- 2. S/N is;

 $S/N = 20 \log \left(\frac{VoAF (mVrms)}{VN (mVrms)} \right) (dB)$

C_{QIF} QIF Control

Lower the voltage of V9, and measure the voltage of V9 when DC voltage of TP15 begins to change.

The Note in The System Setup

M52342FP has 2 power supply pins of V_{CC} (pin 16, 17) and Vreg. OUT (pin 20, 21) . V_{CC} is for AFT output, RF AGC output circuits and 5 V regulated power circuit and Vreg. OUT is for the other circuit blocks.

In case M52342FP is used together with other ICs like VIF operating at more than 5 V, the same supply voltage as that of connected ICs is applied to V_{CC} and Vreg. OUT is opened. The other circuit blocks, connected to Vreg. OUT are powered by internal 5 V regulated power supply.

In case the connecting ICs are operated at 5 V, 5 V is supplied to both V_{CC} and Vreg. OUT.

Logic Table

		AF	AFT
10 k "H"	20 k "H"	NTSC	DEFEAT
	20 k "L"		NORMAL
10 k "L"	20 k "H"	PAL	DEFEAT
	20 k "L"		NORMAL

Input Signal

SG No.	Signals (50 Ω Termination)
1	$f_0 = 58.75 \text{ MHz}$ AM 20 kHz 77.8% 90 dB μ
2	$f_0 = 58.75 \text{ MHz} 90 \text{ dB}\mu \text{ CW}$
3	$f_1 = 58.75 \text{ MHz} 90 \text{ dB}\mu \text{ CW}$ (Mixed signal)
	$f_2 =$ Frequency variable 70 dB μ CW (Mixed signal)
4	$f_0 = 58.75 \text{ MHz}$ AM 20 kHz 77.8% level variable
5	$f_0 = 58.75 \text{ MHz}$ AM 20 kHz 14.0% level variable
6	$f_0 = 58.75 \text{ MHz} 80 \text{ dB}\mu \text{ CW}$
7	$f_0 = 58.75 \text{ MHz} 110 \text{ dB}\mu \text{ CW}$
8	$f_0 = 58.75 \text{ MHz} \text{ CW}$ level variable
9	$f_0 = variable AM 20 \text{ kHz} 77.8\% 90 dB\mu$
10	$f_0 = variable 90dB\mu CW$
11	$f_1 = 58.75 \text{ MHz} 90 \text{ dB}\mu \text{ CW}$ (Mixed signal)
	$f_2 = 55.17 \text{ MHz} 80 \text{ dB}\mu$ CW (Mixed signal)
	$f_3 = 54.25 \text{ MHz } 80 \text{ dB}\mu \text{ CW (Mixed signal)}$
12	$f_0 = 58.75 \text{ MHz} 87.5\%$
	TV modulation ten-step waveform
	Sync tip level 90 dBµ
13	$f_1 = 54.25 \text{ MHz} 95 \text{ dB}\mu \text{ CW}$
14	$f_1 = 54.25 \text{ MHz} 75 \text{ dB}\mu \text{ CW}$
15	$f_1 = 58.75 \text{ MHz} 90 \text{ dB}\mu$ CW (Mixed signal)
	$f_2 = 54.25 \text{ MHz} 70 \text{ dB}\mu \text{ CW}$ (Mixed signal)
16	$f_0=4.5~\text{MHz}~90~\text{dB}\mu~\text{FM}~400~\text{Hz}\pm25~\text{kHz}~\text{dev}$
17	$f_0 = 4.5 \; \text{MHz} \; \; \text{FM} \; 400 \; \text{Hz} \pm 25 \; \text{kHz} \; \text{dev} \;$ level variable
18	$f_0 = 4.5 \text{ MHz} 90 \text{ dB}\mu \text{ AM } 400 \text{ Hz} 30\%$
19	$f_0 = 4.5 \text{ MHz} 90 \text{dB}\mu \text{ CW}$
20	$f_0 = 4.5 \text{ MHz} \text{ CW}$ level variable
21	$f_0=5.5~\text{MHz}~90d\text{B}\mu~\text{FM}~400~\text{Hz}\pm50~\text{kHz}~\text{dev}$
22	$f_0 = 5.5 \text{ MHz} \ \text{FM} \ 400 \text{ Hz} \pm 50 \text{ kHz}$ dev level variable
23	$f_0 = 5.5 \text{ MHz} 90 \text{ dB}\mu \text{ AM } 400 \text{ Hz} 30\%$
24	$f_0 = 5.5 \text{ MHz} 90 \text{dB}\mu \text{ CW}$
25	$f_0 = 5.5 \text{ MHz} \text{ CW}$ level variable

Typical Characteristics

Pin Description

Pin 1 (RF AGC DELAY)

Pin 2 (AFT OUT)

Pin 3 (RF AGC OUT)

Pin 4, Pin 5 (VIF IN)

Pin 6, Pin 7, Pin 8 (GND)

Pin 9 (QIF DET IN)

Pin 10 (IF AGC FILTER)

Pin 11 (NFB)

Pin 12 (AUDIO OUT)

Pin 13 (LIMITER IN)

Pin 14 (AFT SW/NPSW)

It works as a switch by connecting the resistor to 5 V (High) or GND (Low), alternately.

				Pin 14
10k	20k	AF AMP	AFT	Applied Voltage
Н	Н	4.5 MHz	Defeat	4.4 to 5.0 V
Н	L	4.5 MHz	Normal	2.7 to 4.0 V
L	Н	Other	Defeat	1.0 to 2.3 V
L	L	Other	Normal	0 to 0.6 V

The terminal voltage is set by the external resistors because of an open base input.

Pin 15 (QIF OUT)

Pin 16, Pin 17 (V_{cc})

Pin 18, Pin 19 (VCO COIL)

Pin 20, Pin 21 (Vreg. OUT)

Pin 22 (VIDEO OUT)

Pin 23 (APC FILTER)

Pin 24 (EQ F/B)

Package Dimensions

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